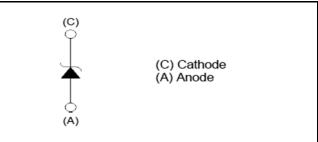


V _R	1200V
I _F	30Å ^{*1}
Q _C	82nC

Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible

Inner Circuit



Construction

Silicon carbide epitaxial planar type

Schottky diode

• Absolute Maximum Ratings ($T_i = 25^{\circ}C$)

	U			
Parameter		Symbol	Value	Unit
Reverse voltage (repetitive peak)		V _{RM}	1200	V
Reverse voltage (DC)		V _R	1200	V
Continuous forward current		I _F	30	А
Surge non- repetitive forward current	PW=10ms sinusoidal, T _j =25°C	^{*2} ا _{FSM}	190	А
	PW=10ms sinusoidal, T _j =150°C		140	А
	PW=10µs square, T _j =25°C		780	А
i ^² t value	$1 \leq PW \leq 10ms, T_j=25^{\circ}C$	$\int i^2 dt^2$	195	A ² s
	$1 \leq PW \leq 10ms, T_j=150^{\circ}C$	Ji ² dt	109	A ² s
Junction temperature		Τ _j	175	°C
Range of storage temperature		T _{stg}	-55 to +175	°C

*1 Limited by T_j *2 Assumes $Z_{th(j-a)}$ of 0.36 °C/W or less. (Pulse Width = 8.3ms)

•Electrical characteristics ($T_j = 25^{\circ}C$)

Deremeter	Symbol	Conditions	Values			
Parameter		Conditions	Min.	Тур.	Max.	Unit
DC blocking voltage	V _{DC}	I _R =0.6mA	1200	-	-	V
	V _F	I _F =30A,T _j =25°C	-	1.4	1.6	V
Forward voltage		I _F =30A,T _j =150°C	-	1.8	-	V
		I _F =30A,T _j =175°C	-	1.9	-	V
	I _R	V _R =1200V,T _j =25°C	-	30	600	μA
Reverse current		V _R =1200V,T _j =150°C	-	240	-	μA
		V _R =1200V,T _j =175°C	-	390	-	μA
Total conscitance	С	V _R =1V,f=1MHz	-	1600	-	pF
Total capacitance		V _R =800V,f=1MHz	-	130	-	pF
Total capacitive charge	Q _C	V _R =800V,di/dt=500A/µs	-	82	-	nC
Switching time	t _C	V _R =800V,di/dt=500A/μs	-	27	-	ns

•Electrical characteristic curves

Fig.1 V_F - I_F Characteristics

Fig.3 V_R - I_R Characteristics

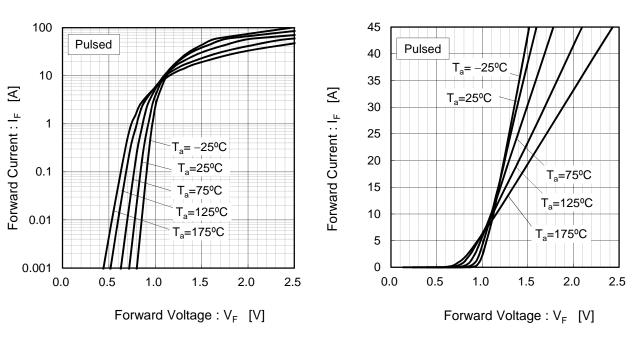
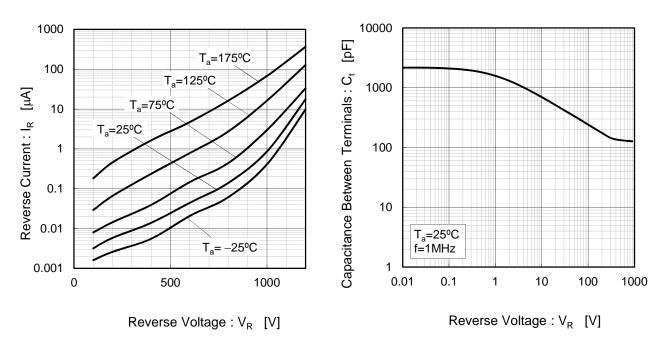




Fig.2 V_F - I_F Characteristics



•Electrical characteristic curves

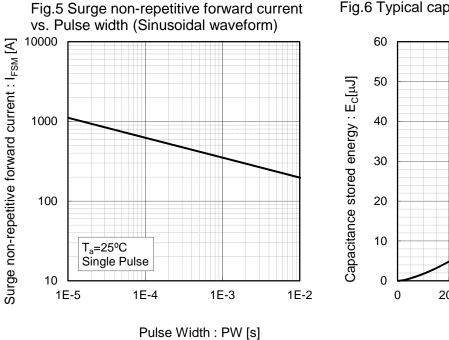
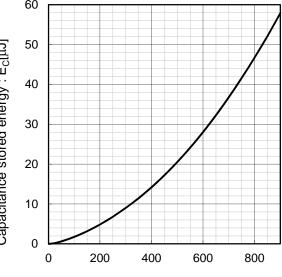
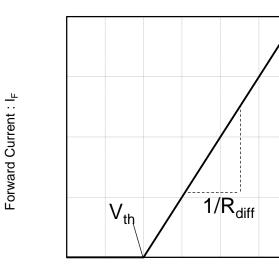


Fig.6 Typical capacitance store energy



Reverse Voltage : V_R [V]

Fig.7 Equivalent forward current curve



Forward Voltage : V_F

 $V_F = V_{th} + R_{diff} I_F$

V _{th} ($T_j) = a_0$	₀ + a ₁ T _j	
R_{diff} (T_j) = b ₀	$_{0} + b_{1} T_{j}$	$+ b_2 T_j^2$

Symbol	Typical Value	Unit
a ₀	9.93E-01	V
a ₁	-1.27E-03	V/°C
b ₀	1.22E-02	Ω
b ₁	6.87E-05	Ω/°C
b ₂	4.43E-07	$\Omega/^{\circ}C^{2}$

 T_{i} in °C; -55 °C < T_{i} < °C; I_{F} < 60A

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Unit Quantity	
Minimum Package Quantity	
Packing Type	
Constitution Materials List	inquiry
RoHS	Yes